

GODDARD SPACE FLIGHT CENTER

Test Lab Report Summary

<i>Report Number:</i>	Q10164	<i>Project:</i>	SWIFT
<i>Part Type:</i>	Microcircuit	<i>System:</i>	BAT
<i>Part Number:</i>	OP290GS	<i>Initiated Date:</i>	05/01/2001
<i>Date Code:</i>	9739/7P36563.2	<i>Report Date:</i>	06/21/2001
<i>Manufacturer:</i>	Analog Devices	<i>Investigator:</i>	C. Greenwell (562)
<i>Generic Number:</i>	OP290	<i>Requester:</i>	B. Meinhold (562)
<i>Purchase Spec:</i>	Commercial	<i>Approval / Date:</i>	

Step 1: INCOMING INSPECTION

<u>Test</u>	<u>Quantity</u>	<u>Passed</u>	<u>Failed</u>
External Visual	N/A	N/A	N/A
PIND Condition A	N/A	N/A	N/A

Step 2: DESTRUCTIVE PHYSICAL ANALYSIS

Destructive Physical Analysis (DPA) was conducted per GSFC document “Plastic Encapsulated Microcircuit (PEM) Guidelines for Screening and Qualification for Space Applications”, except that cross-section was done without dye penetrant and glassivation integrity testing was not performed.

No rejectable defects or anomalies were observed during this analysis.

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Summary of Analysis:

	<i>Serial Number</i>	<u>I6</u>	<u>M7</u>	<u>M9</u>	<u>M11</u>	<u>N9</u>
<i>External Examination</i>						
1. Markings - legibility and correctness _____		A	A	A	A	A
2. Integrity of package seals _____		N/A	N/A	N/A	N/A	N/A
3. Condition of external leads and plating _____		A	A	A	A	A
4. Overall package condition _____		A	A	A	A	A
<i>Radiographic Examination</i>						
5. Die bonding material and die alignment _____		A	A	A	A	A
6. Package seal integrity _____		N/A	N/A	N/A	N/A	N/A
7. Presence of foreign material _____		A	A	A	A	A
8. Lead dress (if revealed) _____		A	A	A	A	A
<i>Acoustic Microscopy Inspection</i>						
9. Condition of material interfaces (delaminations) _____		A	A	A	A	A
10. Condition of molding material (voids, cracks) _____		A	A	A	A	A
<i>Internal Examination (including cross-section)</i>						
11. Presence of foreign material _____		A	A	A	A	A
12. Mechanical condition of die _____		A	A	A	A	A
13. Wire bonds and lead dress _____		A	A	A	A	A
14. Die bonding material _____		A	A	A	A	A
15. Condition of die surface _____		A	A	A	A	A
16. Condition of metallization _____		A	A	A	A	A
17. SEM Examination _____		N/P	A	A	A	N/P
<i>Bond Strength</i>						
18. Strength _____		N/P	A	A	A	N/P
19. Metallization adherence _____		N/P	A	A	A	N/P
<i>Die Bond Strength</i>						
20. Strength _____		N/P	N/P	N/P	N/P	N/P

SN's I6 and N9 subjected to cross-sectional examination.

(* = Refer to comments, A = acceptable, U = unacceptable, N/A = not applicable, N/P = not performed)

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Appended Photographs:

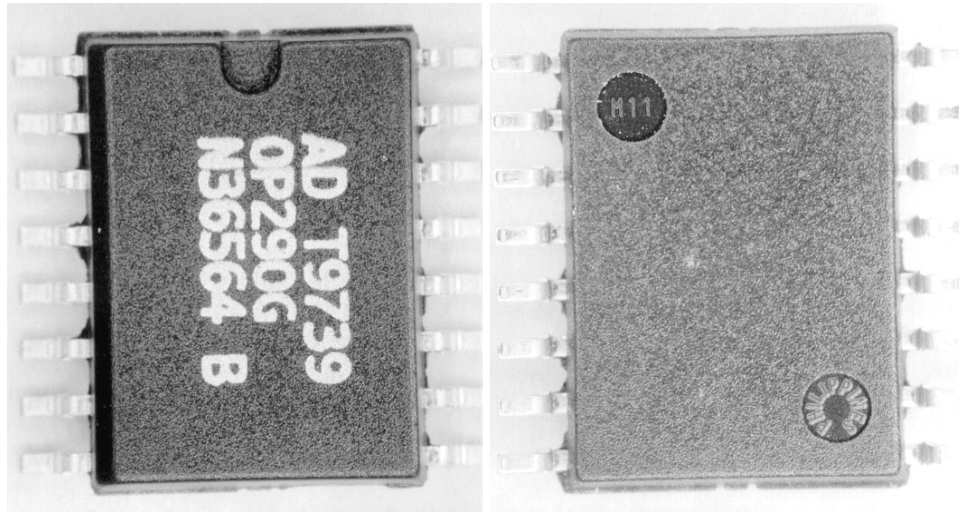


Figure 1. External top and bottom views of the OP290GS devices. Each device had a unique two character alphanumeric code that was used for reference designations during this analysis. 6X

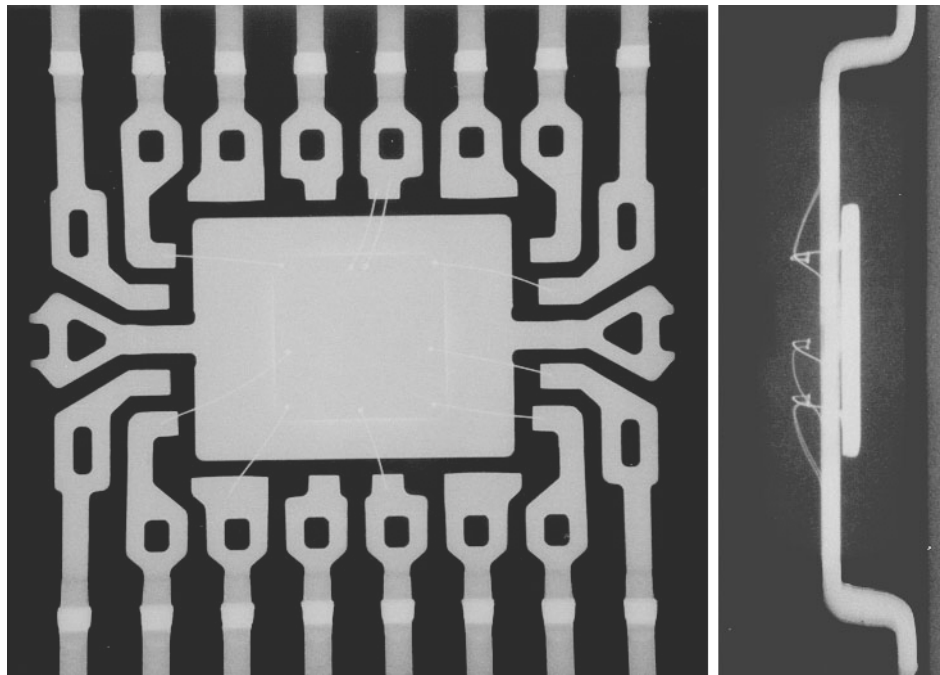


Figure 2. Top and side view radiographic images. 8X

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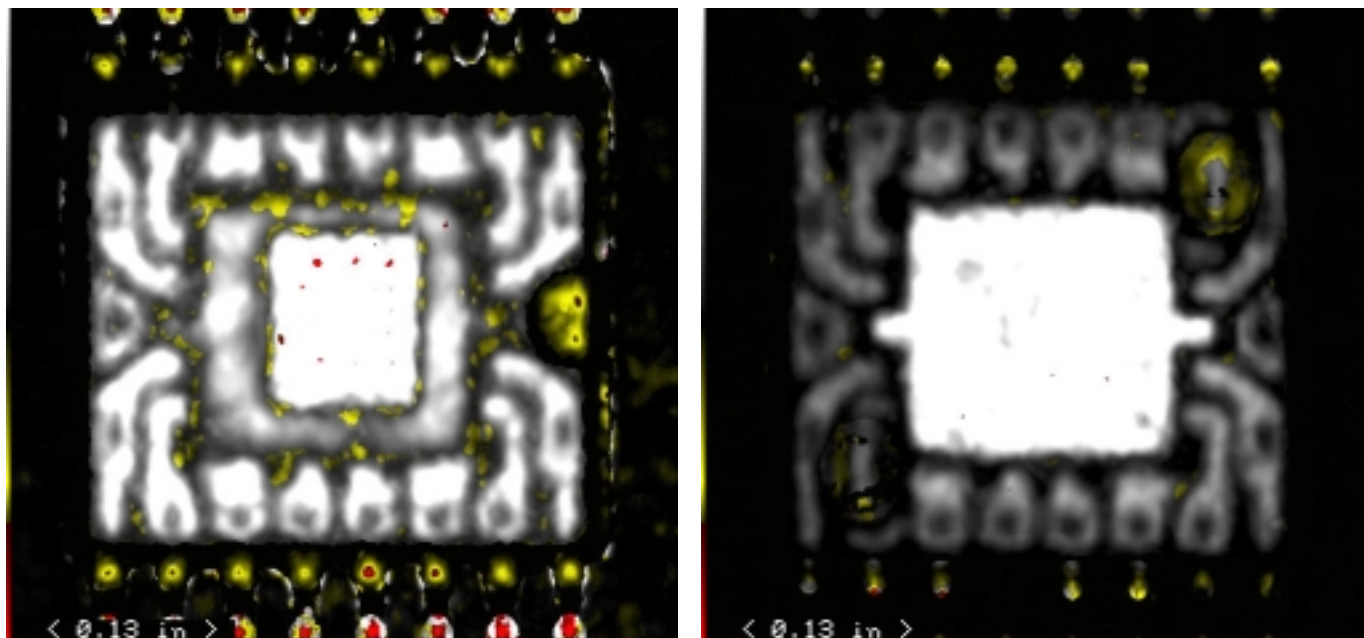


Figure 3. Top (left) and bottom C-SAM images of SN I6.

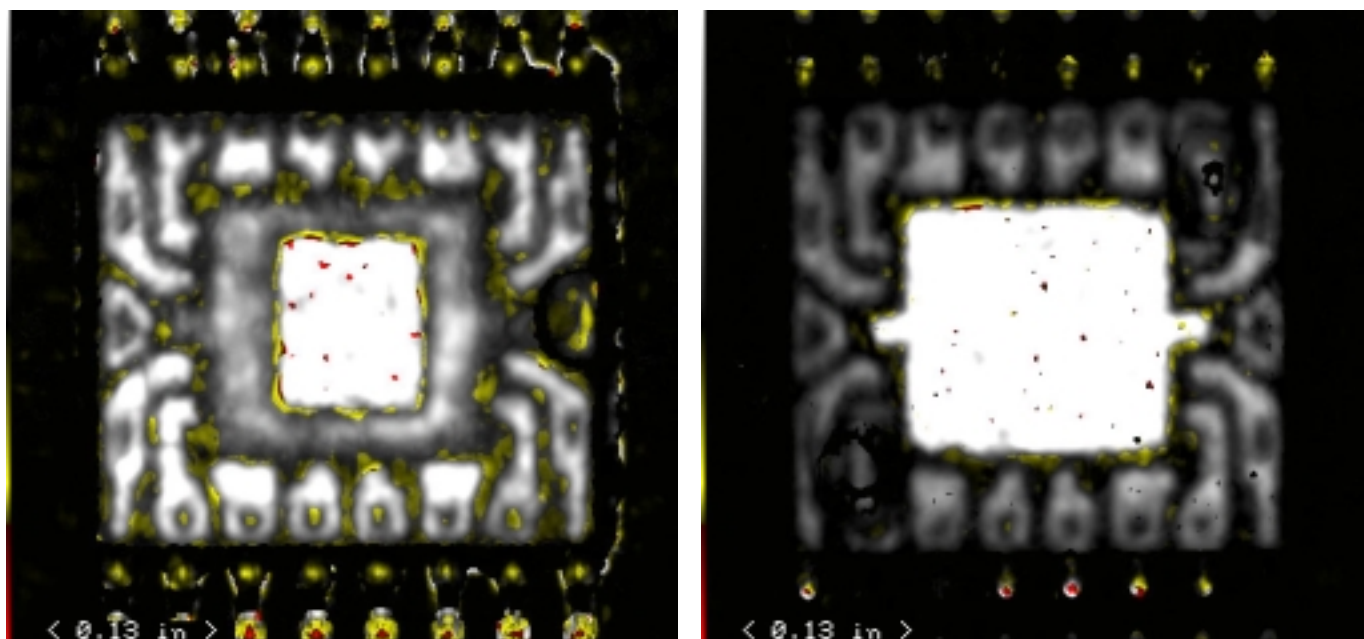


Figure 4. Top (left) and bottom C-SAM images of SN M7.

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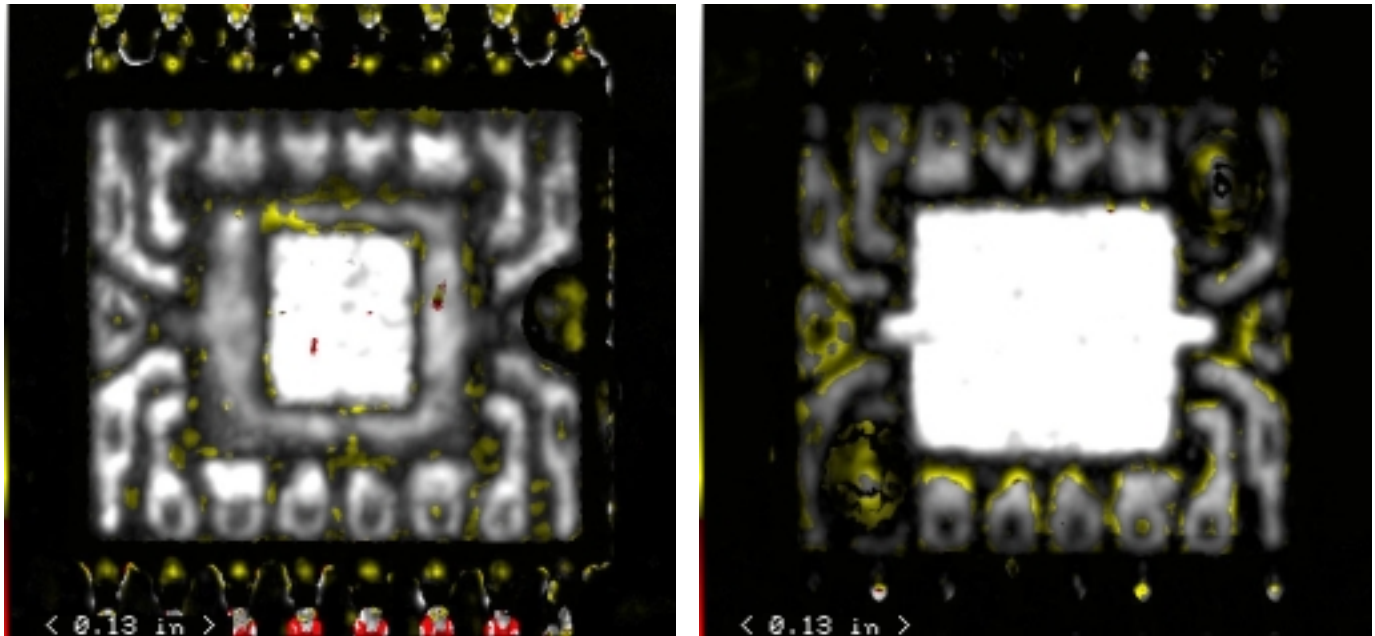


Figure 5. Top (left) and bottom C-SAM images of SN M9.

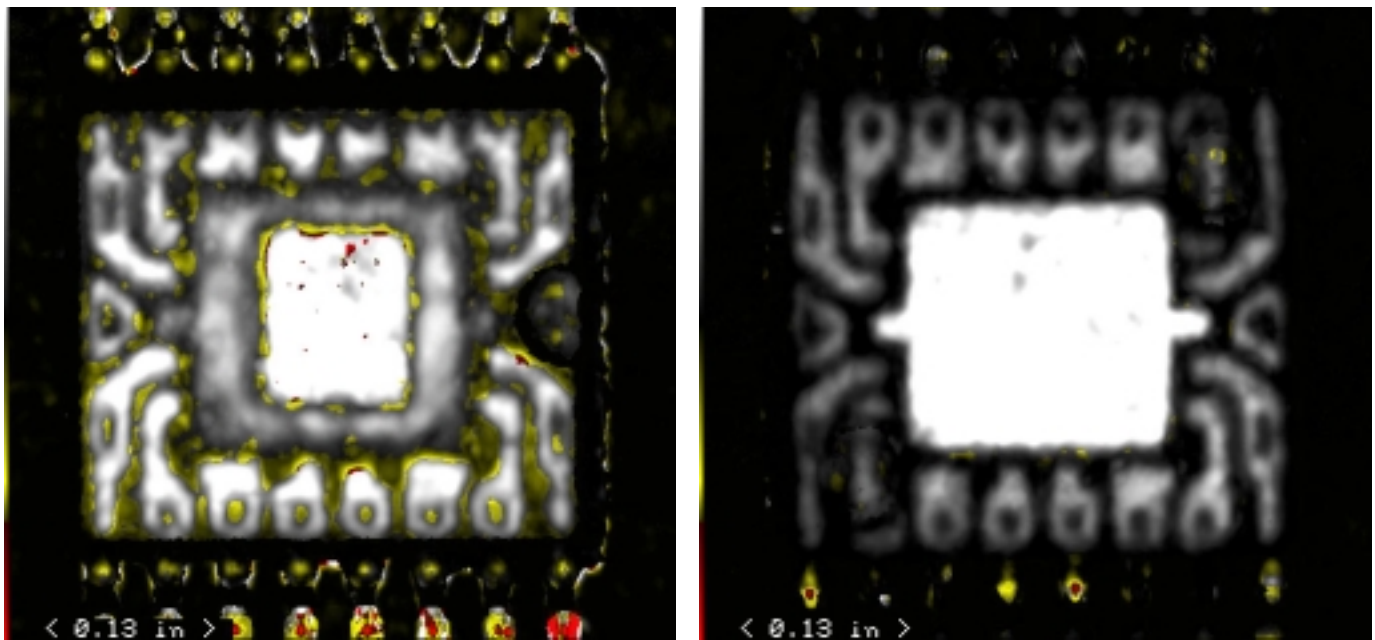


Figure 6. Top (left) and bottom C-SAM images of SN M11.

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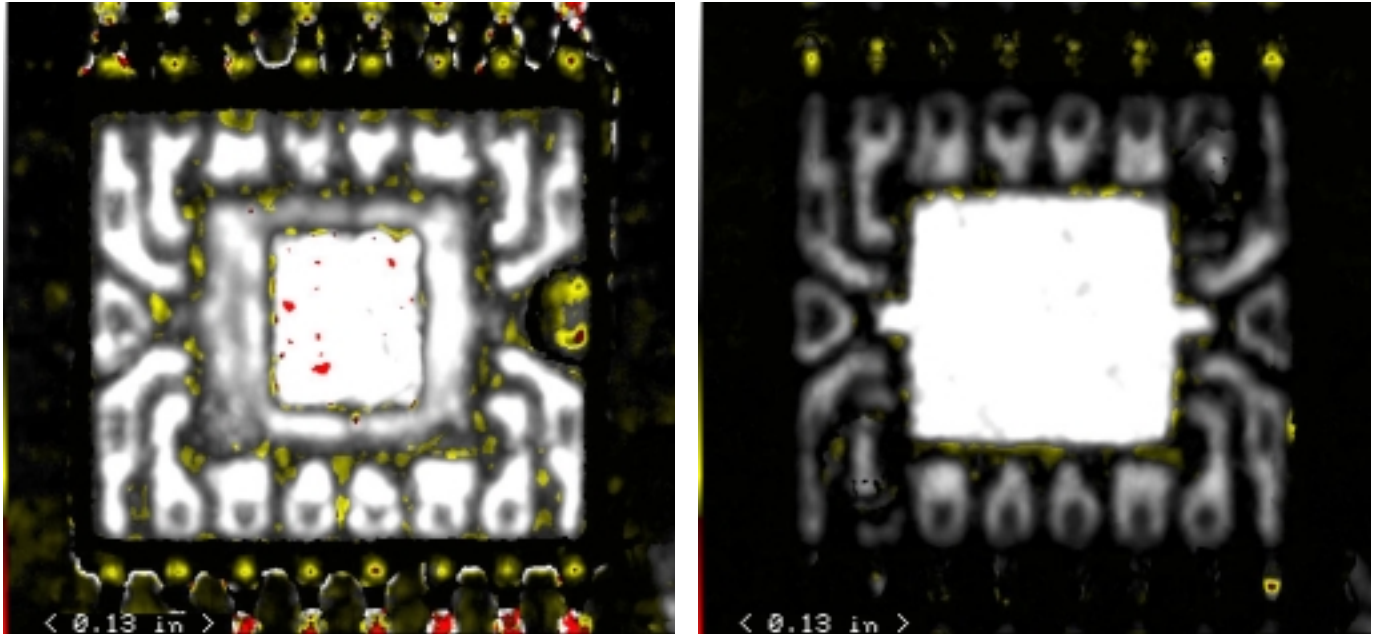


Figure 7. Top (left) and bottom C-SAM images of SN N9.

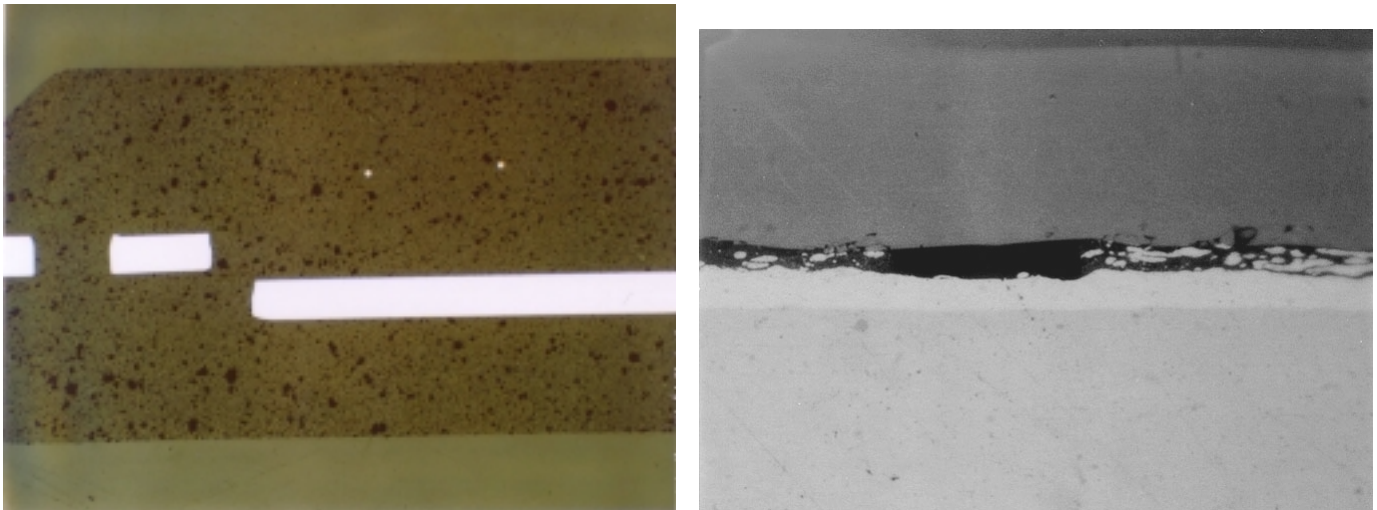


Figure 8. Cross-section images of SN N9. The right side image shows an area of die attach void. The die is on the top side of the image and the plated die paddle is at the bottom. No delaminations or anomalies were observed, consistent with the C-SAM inspection results. Left image $\approx 100X$; right $\approx 1000X$.

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Figure 9. Cross-section images of SN I6. This image shows a hillock formation on the die metallization. No delaminations or anomalies were observed. 1000X.

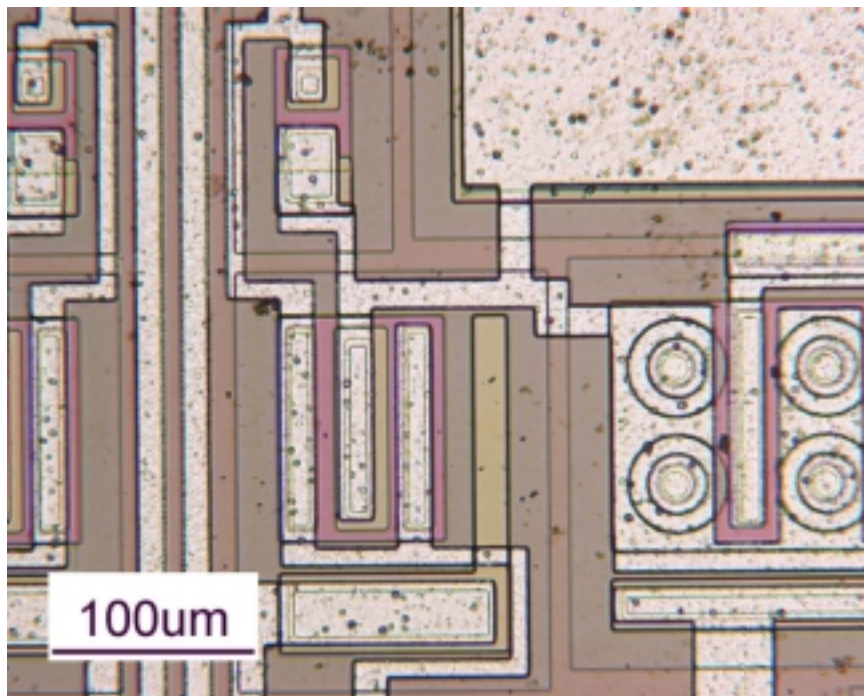


Figure 10. Optical micrograph shows general die features on SN M7. The speckles on the die surface are deprocessing artifact.

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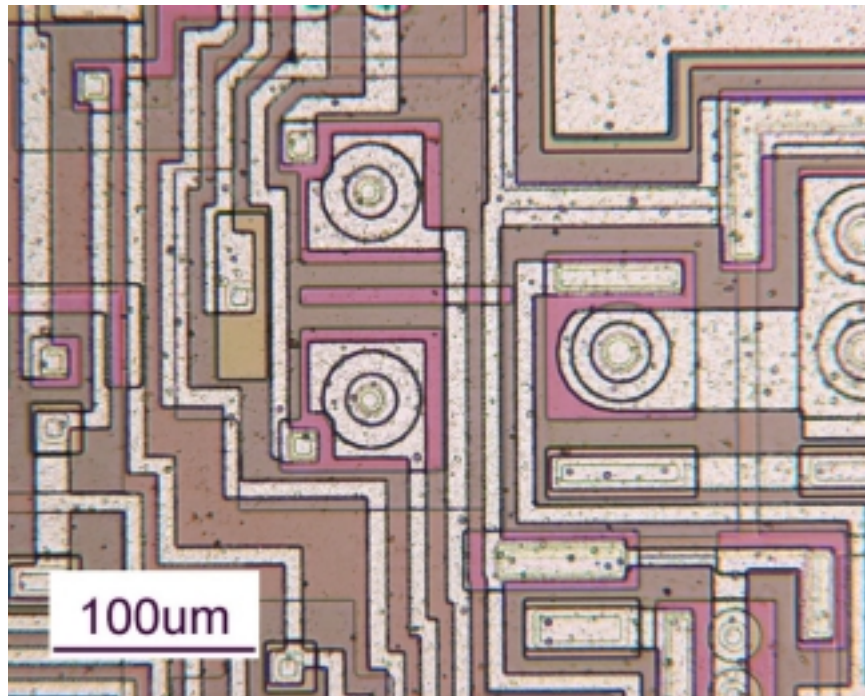


Figure 11. Optical micrograph image of M9 shows general die features.

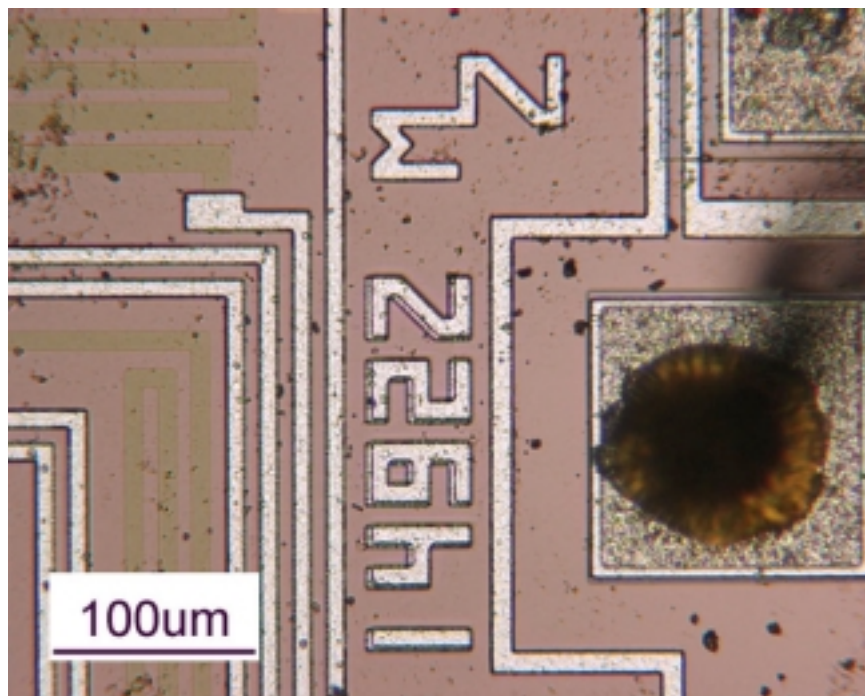


Figure 12. Optical micrograph image shows worst case bond placement on SN M11. Discoloration of the bond pad is due to the acid deprocessing

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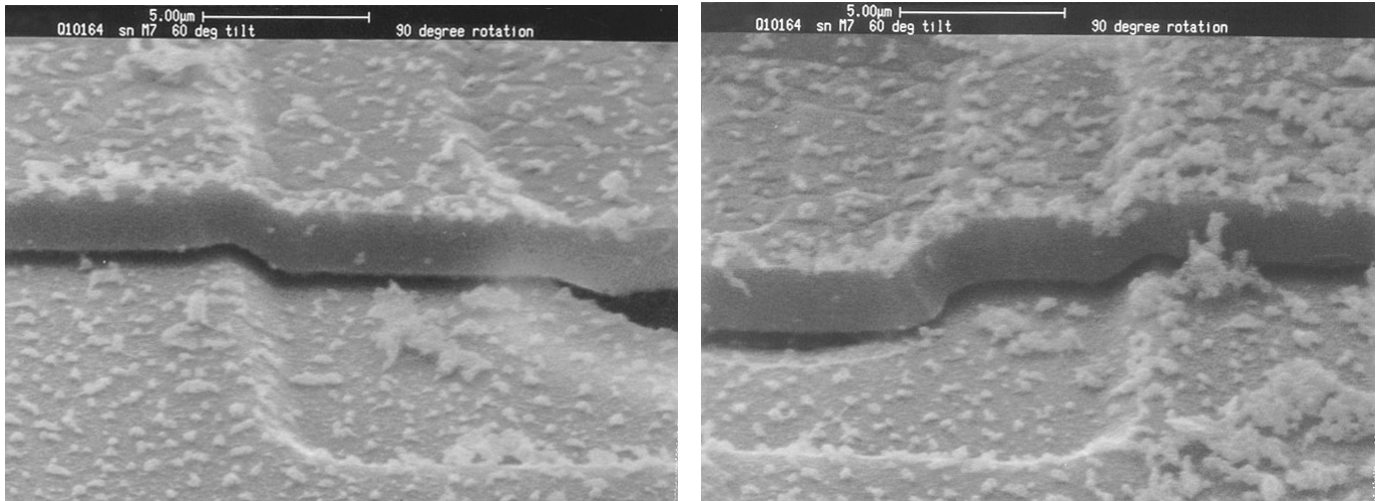


Figure 13. SEM micrographs of SN M7. The metallization has excellent step coverage. All three DPA samples have etch residue throughout the die surfaces; an artifact of the etch process.

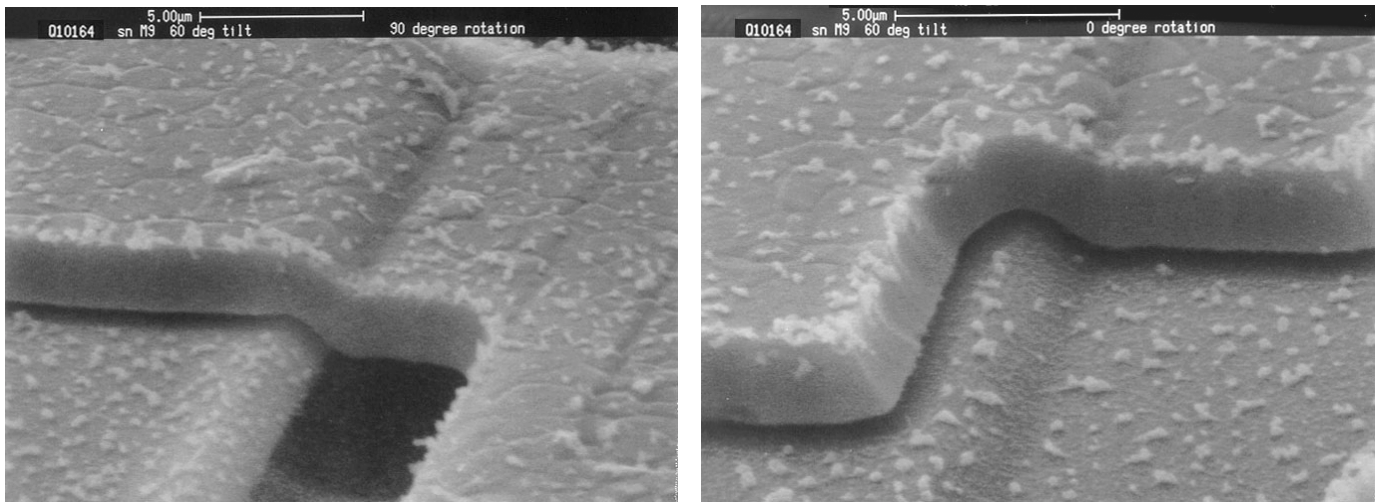


Figure 14. SEM micrographs of SN Q8.

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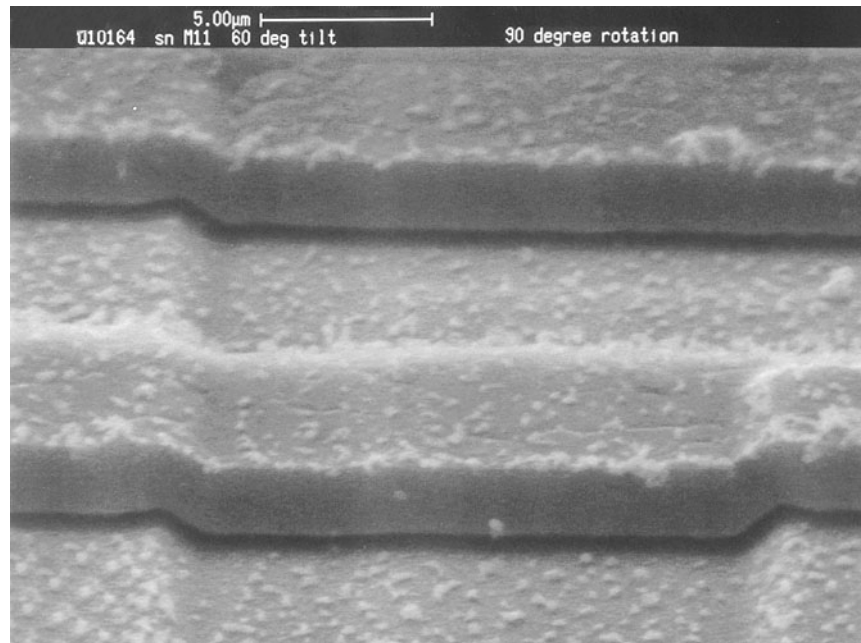


Figure 15. SEM micrograph of SN M11.



Figure 16. SEM micrographs of SN M11.